

# **AD162C Datasheet**

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**Version: 1.2**

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## AD162C Features

### CPU

- 32bit DSP
- Maximum speed 160MHz
- Interrupts with 8 priority level

### Memory

- OTP
- Optional built-in flash memory

### Clocks

- On-chip 16 MHz clock
- On-chip 200KHz lower-temperature-drift clock
- 32.768 KHz crystal oscillator

### DSP Audio Processing

- Support MP2, MP3, WMA, WAV decoding
- Multi-band DRC limiter
- Multi-band EQ configuration for voice Effects

### Audio Codec

- Two channels 16-bit DAC, single-ended with SNR  $\geq$  93dB, differential with SNR  $\geq$  100dB
- One channel 24-bit ADC, SNR  $\geq$  85dB
- Audio DAC Sampling rates of 8KHz/11.025KHz/16KHz/22.05KHz/24KHz/32KHz/44.1KHz/48KHz/64KHz/88.2KHz/96KHz are supported
- Audio ADC Sampling rates of 8KHz/11.025KHz/16KHz/22.05KHz/24KHz/32KHz/44.1KHz/48KHz are supported
- Audio DAC support single-ended and differential cap-less mode
- Support analog audio input
- Support for driving 16 or 32 ohm speaker

### Peripherals

- One full speed USB OTG controller
- One SD host controller for MMC/SD
- Three multi-function 32-bit timers, support capture and PWM mode
- UART0 controller
- The UART1 supports DMA and flow control
- One IIC Master controller
- Two SPI Master / Slaver controller with DMA
- One QDEC interface
- 7-channel 10-bit general purpose ADC
- 4-channel Advance PWM controller
- 9 Individually programmable and multiplexed GPIO pins
- Digital peripheral crossbar
- Up to 9 external interrupt / wake-up source ( low power available, can be multiplexed to any I/O )

### PMU

- Built-in lithium battery charging manager, up to 120mA charging current
- RTC Alarm Wakeup
- Less than 2uA soft off current
- VPWR range : 4.5V to 6.0V
- VBAT range : 2.2V to 5.0V
- IOVDD range : 2.1V to 3.6V

### Packages

- SOP16

### Temperature

- Operating temperature: -40°C to +85°C
- Storage temperature: -65°C to +150°C

### Applications

- Audio player
- Microcontrollers

# 1 Block Diagram

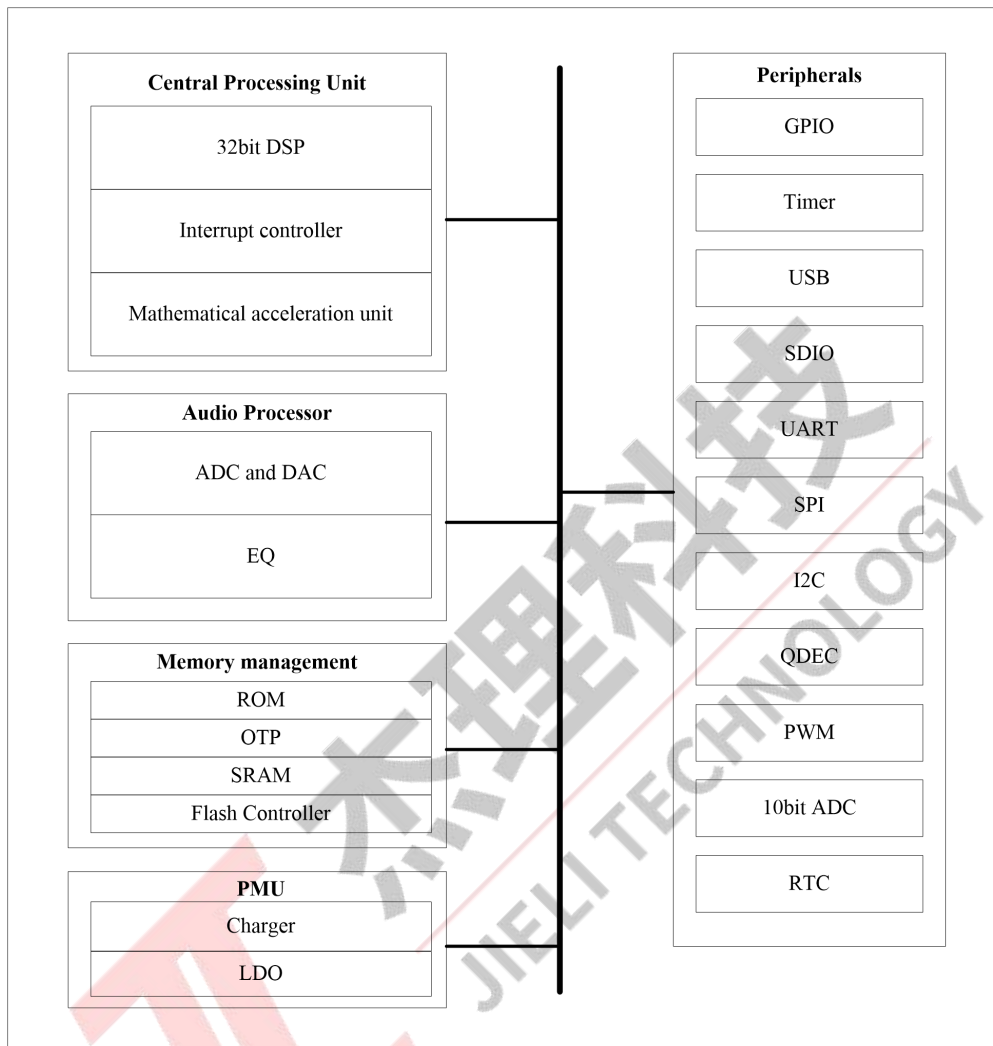


Figure 1-1 AD162C Block Diagram

## 2 Pin Definition

### 2.1 Pin Assignment

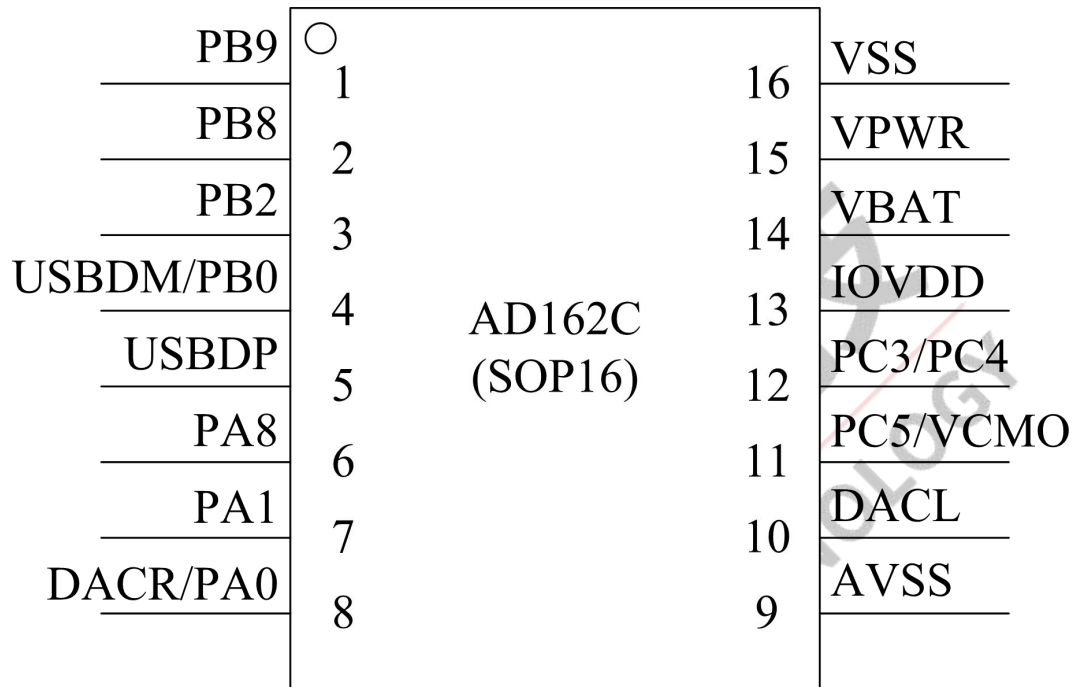


Figure 2-1 AD162C Package Diagram

## 2.2 Pin Description

Table 2-1 AD162C Pin Description

PIN NO.	Name	Type	Function	Other Function
1	PB9	I/O	GPIO	ROSCI_32K:32.768KHz crystal oscillator input; CLKOUT2:Clock Out2;
2	PB8	I/O	GPIO	ROSCO_32K:32.768KHz crystal oscillator output; ADC10:ADC Input Channel 10; CLKOUT1:Clock Out1;
3	PB2	I/O	GPIO	ADC6:ADC Input Channel 6;
4	PB0	I/O	GPIO	ADC5:ADC Input Channel 5;
	UDBDM	I/O	USB Negative Data (pull down)	SPI1DO(A):SPI1 Data Out(A); IIC0_SDA(A):IIC0 SDA(A); UART0RXA:Uart0 Data Input(A); ADC15:ADC Input Channel 15;
5	USBDP	I/O	USB Positive Data (pull down)	SPI1CLKA:SPI1 Clk(A); IIC0_SCL(A):IIC0 SCL(A); UART0TXA:Uart0 Data Output(A); ADC14:ADC Input Channel 14;
6	PA8	I/O	GPIO (pull up)	Long press reset; ADC3:ADC Input Channel 3;
7	PA1	I/O	GPIO	MICIN0:MIC0 Input Channe; UART1RXB:Uart1 Data Input(B); TMR0:Timer0 Clock Input;
8	PA0	I/O	GPIO	MICLDO:Microphone linear voltage regulator output; ADC0:ADC Input Channel 0; UART1TXB:Uart1 Data Output(B); PWM0:Timer0 PWM Output;
	DACR	AO		Right channel audio output;
9	AVSS	G		Audio ground;
10	DACL	AO		Left channel audio output;
11	VCMO	AO		negative of earphone;
	PC5	I/O	GPIO	AINR:Right channel analog audio input;
12	PC4	I/O	GPIO	AINL:Left channel analog audio input; TMR2:Timer2 Clock Input;
	PC3	I/O	GPIO	SDPG:SD card Power Gate; ADC13:ADC Input Channel 13;
13	IOVDD	PO	Power supply for GPIO	Built-in linear voltage regulator output;
14	VBAT	P		Battery interface;

15	VPWR (PP0)	PI (I/O)	GPIO	Charge Power Input; UART1TXA:Uart1 Data Output(A); UART1RXA:Uart1 Data Input(A); CAP1:Timer1 Capture;
16	VSS	G		System ground;

Pin Type	Description	Pin Type	Description
P	Power	I/O	Input or Output
PI	Power Input	I	Input
PO	Power Output	O	Output
AO	Analog Output	G	Ground



### 3 Electrical Characteristics

#### 3.1 Absolute Maximum Ratings

Table 3-1

Symbol	Parameter	Min	Max	Unit
T <sub>opt</sub>	Operating temperature	-40	+85	°C
T <sub>stg</sub>	Storage temperature	-65	+150	°C
V <sub>BAT</sub>	Supply Voltage	-0.3	5.0	V
V <sub>PWR</sub>	Charger Voltage	-0.3	6.0	V
V <sub>IOVDD</sub>	Voltage applied at IOVDD	-0.3	3.6	V
V <sub>GPIO</sub>	Voltage applied to GPIO	-0.3	IOVDD+0.3	V

Note : The chip can be damaged by any stress in excess of the absolute maximum ratings listed below

#### 3.2 PMU Characteristics

Table 3-2

Symbol	Parameter	Min	Typ	Max	Unit	Test Conditions
V <sub>BAT</sub>	Voltage Input	2.2	3.7	5.0	V	-
V <sub>PWR</sub>	Charger supply Voltage	4.5	5.0	6.0	V	-
IOVDD	Voltage output	2.1	3.0	3.6	V	V <sub>BAT</sub> = 4.2V, 10mA loading
	Loading current	-	-	100	mA	IOVDD=3.3V@V <sub>BAT</sub> = 3.6V
V <sub>LVD</sub>	Voltage input	2.1	2.8	2.8	V	Low-Voltage Detection of IOVDD

#### 3.3 Battery Charge

Table 3-3

Symbol	Parameter	Min	Typ	Max	Unit	Test Conditions
V <sub>PWR</sub>	Charge Input Voltage Range	4.5	5	6.0	V	-
V <sub>BAT Float</sub>	Battery Charge Termination Voltage	4.15	4.2	4.25	V	V <sub>PWR</sub> > 4.5V
		4.30	4.35	4.40	V	V <sub>PWR</sub> > 4.65V
I <sub>BAT</sub>	Fast Charge Current	20	-	120	mA	V <sub>BAT</sub> =4.0V@V <sub>PWR</sub> =5.0V
I <sub>END</sub>	Charge Termination Current Threshold	2	-	12	mA	CHG_IIFULL_S==0,1
V <sub>Trikl</sub>	Trickle Charge Voltage	-	3.0	-	V	V <sub>PWR</sub> > 4.5V
I <sub>Trikl</sub>	Trickle Charge Current	2	-	12	mA	V <sub>BAT</sub> < V <sub>Trikl</sub>

### 3.4 IO Input/Output Electrical Logical Characteristics

Table 3-4

GPIO input characteristics						
Symbol	Parameter	Min	Typ	Max	Unit	Test Conditions
V <sub>IL</sub>	Low-Level Input Voltage	-0.3	–	0.3* IOVDD	V	IOVDD = 3.0V
V <sub>IH</sub>	High-Level Input Voltage	0.7* IOVDD	–	IOVDD+0.3	V	IOVDD = 3.0V
GPIO output characteristics						
Symbol	Parameter	Min	Typ	Max	Unit	Test Conditions
V <sub>OL</sub>	Low-Level Output Voltage	–	–	0.1* IOVDD	V	IOVDD = 3.0V
V <sub>OH</sub>	High-Level Output Voltage	0.9* IOVDD	–	–	V	IOVDD = 3.0V

### 3.5 Internal Resistor Characteristics

Table 3-5

Port	Drive Current	Internal Pull-Up Resistor	Internal Pull-Down Resistor	Comment
PA0,PA1,PA8 PB0,PB2 PB8,PB9 PC3~PC5	2mA(HD1,HD0=0,0) 5.6mA(HD1,HD0=0,1) 18mA(HD1,HD0=1,0) 30mA(HD1,HD0=1,1)	10K	10K	1. PA8 default pull up 2. USBDM,USBDP default pull down 3. Internal pull-up/pull-down resistance   accuracy ±20%
PP0(VPWR)	1.4mA	10K	10K	
USBDP	27mA	1.5K	15K	
USBDM		180K	15K	

### 3.6 Audio DAC Characteristics

Table 3-6

Parameter	MODE	Min	Typ	Max	Unit	Test Conditions
Frequency Response		20	–	20K	Hz	1KHz/0dB 10k ohm loading With A-Weighted Filter IOVDD>2.7V
Output Swing	Diff (R to L)	–	1.5	–	V <sub>rms</sub>	
	Single-ended	–	750	–	mV <sub>rms</sub>	
THD+N	Diff (R to L)	–	-80	–	dB	
	Single-ended	–	-80	–	dB	
S/N	Diff (R to L)	–	100	–	dB	
	Single-ended	–	93	–	dB	
Dynamic Range	Diff (R to L)	–	100	–	dB	
	Single-ended	–	93	–	dB	



Noise Floor	Diff (R to L)	-	13	-	uVrms	With A-Weighted Filter IOVDD>2.7V
	Single-ended	-	18	-	uVrms	
Crosstalk	Single-ended	-	-93	-	dB	10KHz/0dB 10k ohm loading IOVDD>2.7V
	(R and L ) to VCMO	-	-60	-	dB	10KHz/0dB 32 ohm loading IOVDD>2.7V
	(R and L ) to VCMO	-	-57	-	dB	10KHz/0dB 16 ohm loading IOVDD>2.7V

### 3.7 Audio ADC Characteristics

Table 3-7

Parameter	MODE	Min	Typ	Max	Unit	Test Conditions
Dynamic Range	Single-ended	-	85	-	dB	Fsample=44.1KHz,Gain=-2dB Fin=1KHz @1Vpp NO A-wt 20Hz-20KHz IOVDD>2.7V
		-	72	-	dB	Fsample=44.1KHz,Gain=14dB Fin=1KHz @160mVpp NO A-wt 20Hz-20KHz IOVDD>2.7V
S/N	Single-ended	-	85	-	dB	Fsample=44.1KHz,Gain=-2dB Fin=1KHz @1Vpp NO A-wt 20Hz-20KHz IOVDD>2.7V
		-	72	-	dB	Fsample=44.1KHz,Gain=14dB Fin=1KHz @160mVpp NO A-wt 20Hz-20KHz IOVDD>2.7V
THD+N	Single-ended	-	-78	-	dB	Fsample=44.1KHz,Gain=-2dB Fin=1KHz @1Vpp NO A-wt 20Hz-20KHz IOVDD>2.7V
		-	-70	-	dB	Fsample=44.1KHz,Gain=14dB Fin=1KHz @160mVpp NO A-wt 20Hz-20KHz IOVDD>2.7V

## 4 Package Information

### 4.1 SOP16

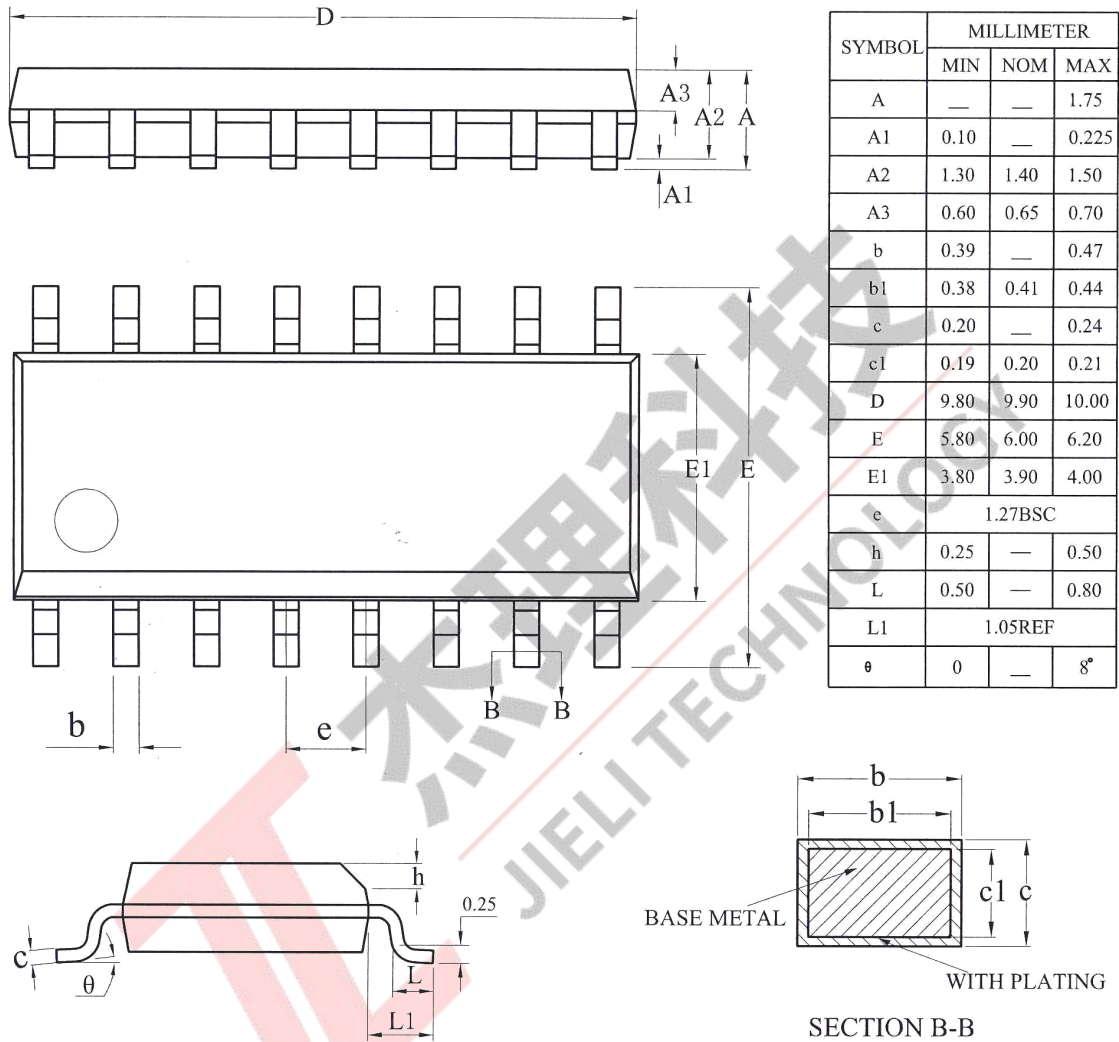
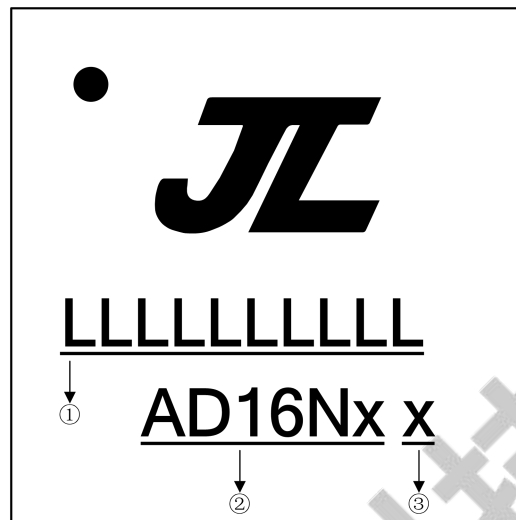


Figure 4-1 AD162C Package

## 5 IC Marking Information



- ① LLLLLLLLLL : Production Batch
- ② AD16Nx : Chip Model
- ③ Built-in flash size
  - 0: No Flash Memory
  - 2: 2Mbit Flash
  - 4: 4Mbit Flash
  - 8: 8Mbit Flash
  - 6: 16Mbit Flash
  - 3: 32Mbit Flash

## 6 Solder-Reflow Condition

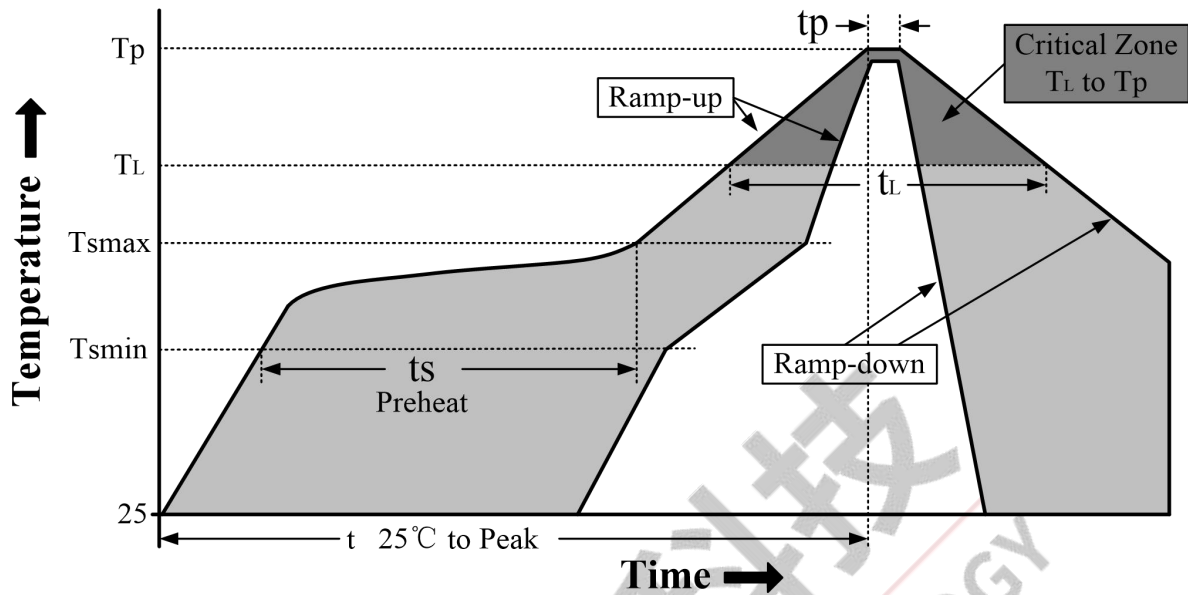


Figure 6-1 Classification Reflow Profile

### Classification Profiles

Table 6-1

Profile Feature		Sn-Pb Eutectic Assembly	Pb-Free Assembly
Preheat/ Soak	Temperature Min (T <sub>smin</sub> )	100 °C	150 °C
	Temperature Max (T <sub>smax</sub> )	150 °C	200 °C
	Time (t <sub>s</sub> ) from (T <sub>smin</sub> to T <sub>smax</sub> )	60-120 seconds	60-180 seconds
Average ramp-up rate (T <sub>smax</sub> to T <sub>p</sub> )		3 °C/second max	3 °C/second max
Liquidous temperature (T <sub>L</sub> )		183 °C	217 °C
Time (t <sub>L</sub> ) maintained above T <sub>L</sub>		60-150 seconds	60-150 seconds
Peak package body temperature (T <sub>p</sub> )		See Table 6-2.	See Table 6-3.
Time within 5°C of actual Peak Temperature (tp)		10-30 seconds	20-40 seconds
Ramp-down rate (T <sub>p</sub> to T <sub>L</sub> )		6 °C/second max.	6 °C/second max.
Time 25 °C to peak temperature		6 minutes max.	8 minutes max.

Note 1: All temperatures refer to topside of the package, measured on the package body surface.

Note 2: Time within 5°C of actual peak temperature (tp) specified for the reflow profiles is a “supplier” minimum and “user” maximum.

### SnPb - Classification Temperature

Table 6-2

Package Thickness	Volume mm <sup>3</sup> < 350	Volume mm <sup>3</sup> ≥ 350
<2.5 mm	240 +0/-5 °C	225 +0/-5 °C
≥ 2.5 mm	225 +0/-5 °C	225 +0/-5 °C

**Pb-free - Classification Temperature**      **Table 6-3**

<b>Package Thickness</b>	<b>Volume mm<sup>3</sup> &lt; 350</b>	<b>Volume mm<sup>3</sup> 350 - 2000</b>	<b>Volume mm<sup>3</sup> &gt; 2000</b>
< 1.6mm	260 °C	260 °C	260 °C
1.6 mm - 2.5mm	260 °C	250 °C	245 °C
> 2.5mm	250 °C	245 °C	245 °C



## 7 Revision History

Date	Revision	Description
2022.09.16	V1.0	Initial Release.
2022.11.28	V1.1	Update Pin Definition. Update VPWR,VBAT range. Update DAC,ADC Test Conditions.
2023.03.22	V1.2	Features modification

